

Ultralow Noise, Low Distortion, Audio Op Amp

FEATURES

- Voltage Noise: 1.2nV/√Hz Max at 1kHz 0.9nV/√Hz Typ at 1kHz
- Voltage and Current Noise 100% Tested
- Gain-Bandwidth Product: 40MHz Min
- Slew Rate: 10V/µs Min
- Voltage Gain: 2 Million Min
- Low THD at 10kHz, $A_V = -10$, $R_L = 600\Omega$: 0.002% $V_O = 7V_{RMS}$
- Low IMD, CCIF Method, A_V = +10: 0.002%

 $R_L = 600\Omega$

 $V_0 = 7V_{RMS}$

APPLICATIONS

- High Quality Audio Preamplifiers
- Low Noise Microphone Preamplifiers
- Very Low Noise Instrumentation Amplifiers
- Low Noise Frequency Synthesizers
- Infrared Detector Amplifiers
- Hydrophone Amplifiers
- Low Distortion Oscillators

DESCRIPTION

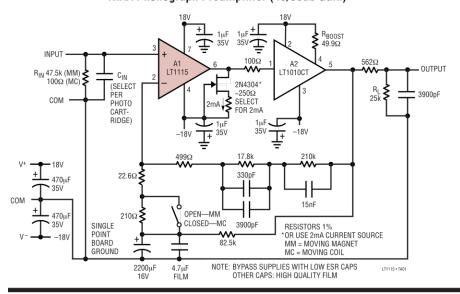
The LT®1115 is the lowest noise audio operational amplifier available. This ultralow noise performance (0.9nV/ $\sqrt{\text{Hz}}$ at 1kHz) is combined with high slew rates (>15V/ μ s) and very low distortion specifications.

The RIAA circuit shown below using the LT1115 has very low distortion and little deviation from ideal RIAA response (see graph).

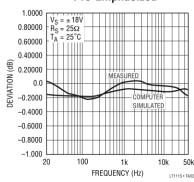
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TYPICAL APPLICATION

RIAA Phonograph Preamplifier (40/60db Gain)



Measured Deviation from RIAA Response. Input at 1kHz = 1mV_{RMS} Pre-Emphasized



1115fa

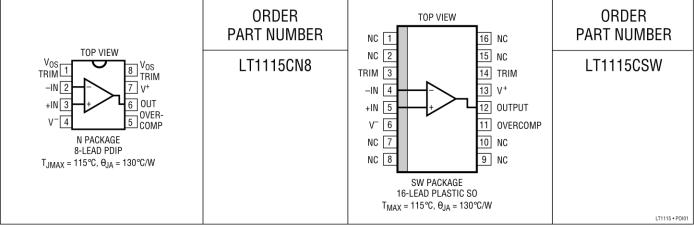


ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage	±22V
Differential Input Current (Note	
Input Voltage	. Équal to Supply Voltage
Output Short-Circuit Duration	Indefinite

PACKAGE DESCRIPTION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS $V_S = \pm 18V$, $T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
THD	Total Harmonic Distortion at 10kHz	$A_V = -10$, $V_O = 7V_{RMS}$, $R_L = 600$		< 0.002		%
IMD	Inter-Modulation Distortion (CCIF)	$A_V = 10, V_0 = 7V_{RMS}, R_L = 600$		< 0.0002		%
V _{os}	Input Offset Voltage	(Note 2)		50	200	μV
I _{os}	Input Offset Current	V _{CM} = 0V		30	200	nA
I _B	Input Bias Current	V _{CM} = 0V		±50	±380	nA
e _n	Input Noise Voltage Density	f _O = 10Hz f _O = 1000Hz, 100% tested		1.0 0.9	1.2	nV/√ <u>Hz</u> nV/√Hz
	Wideband Noise	DC to 20kHz		120		nV _{RMS}
	Corresponding Voltage Level re 0.775V			-136		dB
i _n	Input Noise Current Density (Note 3)	f _O = 10Hz f _O = 1000Hz, 100% tested		4.7 1.2	2.2	pA/√Hz pA/√Hz
	Input Resistance Common Mode Differential Mode			250 15		MΩ kΩ
	Input Capacitance			5		pF
	Input Voltage Range		±13.5	±15.0		V



ELECTRICAL CHARACTERISTICS $V_S = \pm 18V$, $T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
CMRR	Common Mode Rejection Ratio	V _{CM} = ±13.5V	104	123		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4V \text{ to } \pm 19V$	104	126		dB
A _{VOL} Large-Signal Volta	Large-Signal Voltage Gain	$R_L \ge 2k\Omega$, $V_0 = \pm 14.5V$	2.0	20		V/µV
		$R_L \ge 1k\Omega$, $V_0 = \pm 13V$	1.5	15		V/µV
		$R_L \ge 600\Omega$, $V_0 = \pm 10V$	1.0	10		V/µV
V _{OUT}	Maximum Output Voltage	No Load	±15.5	±16.5		V
001	Swing	$R_1 \ge 2k\Omega$	±14.5	±15.5		V
		$R_L \ge 600\Omega$	±11.0	±14.5		V
SR	Slew Rate	A _{VCL} = -1	10	15		V/µs
GBW	Gain-Bandwidth Product	f _O = 20kHz (Note 4)	40	70		MHz
Z_0	Open Loop Output Impedance	$V_0 = 0, I_0 = 0$		70		Ω
Is	Supply Current			8.5	11.5	mA

The ullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 18V$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{os}	Input Offset Voltage	(Note 2)	•		75	280	μV
$\Delta V_{OS}/\Delta T$	Average Input Offset Drift				0.5		μV/°C
I _{os}	Input Offset Current	V _{CM} = 0V	•		40	300	nA
I _B	Input Bias Current	V _{CM} = 0V	•		±70	±550	nA
	Input Voltage Range		•	±13	±14.8		V
CMRR	Common Mode Rejection Ratio	V _{CM} = ±13V	•	100	120		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5 V \text{ to } \pm 18 V$	•	100	123		dB
A _{VOL}	Large-Signal Voltage Gain	$R_L \ge 2k\Omega$, $V_0 = \pm 13V$ $R_L \ge 1k\Omega$, $V_0 = \pm 11V$	•	1.5 1.0	15 10		V/μV V/μV
V _{OUT}	Maximum Output Voltage Swing	No Load $R_{L} \ge 2k\Omega$ $R_{L} \ge 600\Omega$	•	±15 ±13.8 ±10	±16.3 ±15.3 ±14.3		V V V
I _S	Supply Current		•		9.3	13	mA

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Input Offset Voltage measurements are performed by automatic test equipment approximately 0.5 sec after application of power.

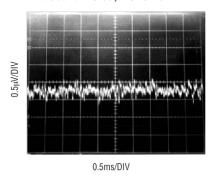
Note 3: Current noise is defined and measured with balanced source resistors. The resultant voltage noise (after subtracting the resistor noise on an RMS basis) is divided by the sum of the two source resistors to obtain current noise.

Note 4: Gain-bandwidth product is not tested. It is guaranteed by design and by inference from the slew rate measurement.

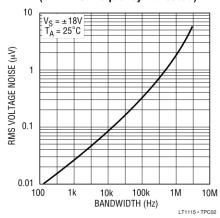
Note 5: The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds $\pm 1.8V$, the input current should be limited to 25mA.



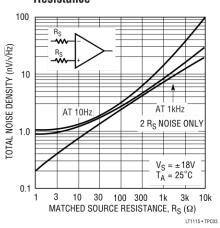
Wideband Noise, DC to 20kHz



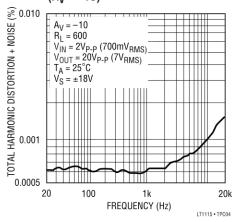
Wideband Voltage Noise (0.1Hz to Frequency Indicated)



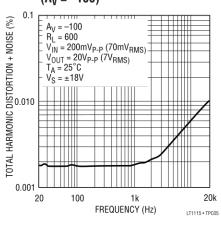
Total Noise vs Matched Source Resistance



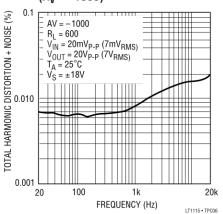
THD + Noise vs Frequency $(A_V = -10)$



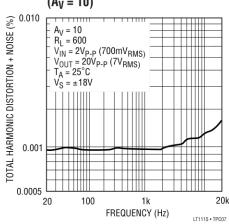
THD + Noise vs Frequency $(A_V = -100)$



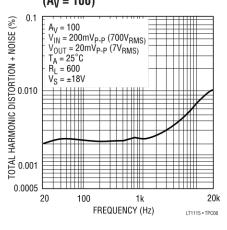
THD + Noise vs Frequency $(A_V = -1000)$



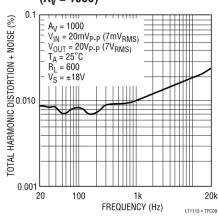
THD + Noise vs Frequency $(A_V = 10)$



THD + Noise vs Frequency $(A_V = 100)$

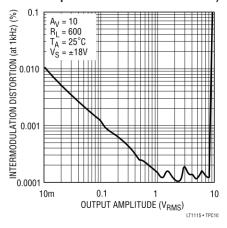


THD + Noise vs Frequency $(A_V = 1000)$

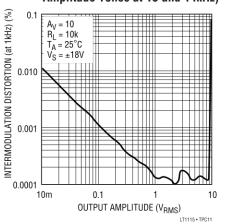


LINEAR

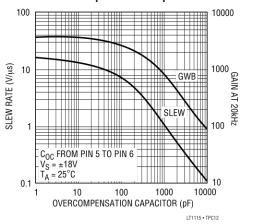
CCIF IMD Test (Twin Equal Amplitude Tones at 13 and 14kHz)*



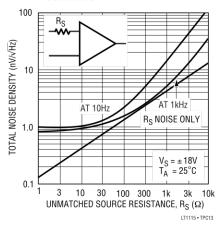
CCIF IMD Test (Twin Equal Amplitude Tones at 13 and 14kHz)*



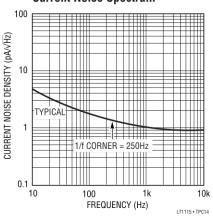
Slew Rate, Gain-Bandwidth-Product vs Overcompensation Capacitor



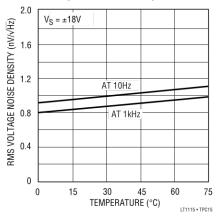
Total Noise vs Unmatched Source Resistance



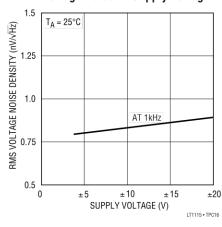
Current Noise Spectrum



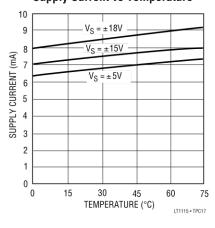
Voltage Noise vs Temperature



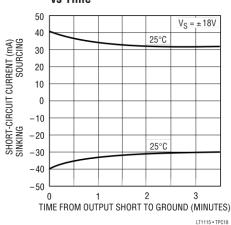
Voltage Noise vs Supply Voltage



Supply Current vs Temperature

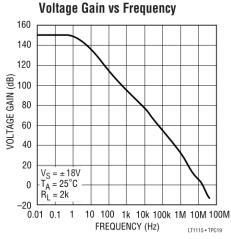


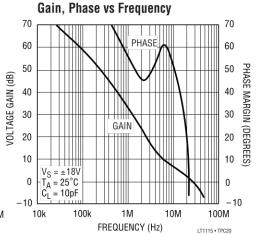
Output Short-Circuit Current vs Time

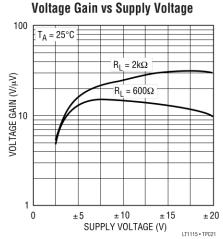


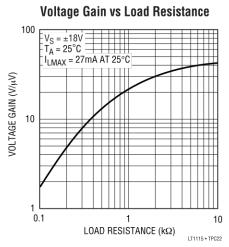
^{*}See CCIF Test Note at end of "Typical Performance Characteristics".

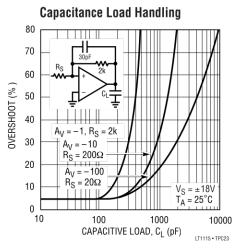


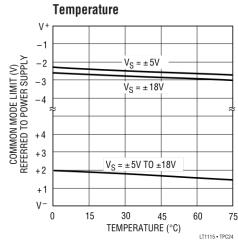




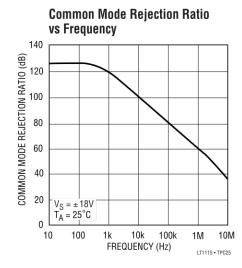


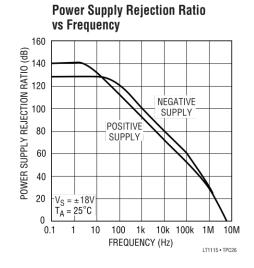


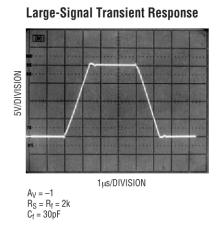




Common Mode Limit Over

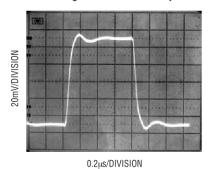






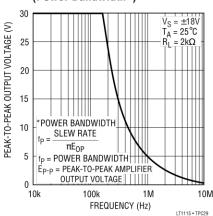
LINEAR

Small-Signal Transient Response

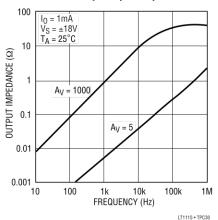


 $A_V = -1,$ $R_S = R_f = 2k\Omega$ $C_f = 30pF$ $C_L = 80pF$

Maximum Output vs Frequency (Power Bandwidth*)



Closed-Loop Output Impedance



CCIF Testing



Note: The CCIF twin-tone intermodulation test inputs two closely spaced equal amplitude tones to the device under test (DUT). The analyzer then measures the intermodulation distortion (IMD) produced in the DUT by measuring the difference tone equal to the spacing between the tones.

The amplitude of the IMD test input is in sinewave peak equivalent terms. As an example, selecting an amplitude of 1.000V will result in the complex IMD signal having the same 2.828V peak-to-peak amplitude that a 1.000V sinewave has. Clipping in a DUT will thus occur at the same input amplitude for THD + N and IMD modes.

APPLICATIONS INFORMATION

The LT1115 is a very high performance op amp, but not necessarily one which is optimized for universal application. Because of very low voltage noise and the resulting high gain-bandwidth product, the device is most applicable to relatively high gain applications. Thus, while the LT1115 will provide notably superior performance to the 5534 in most applications, the device may require circuit modifications to be used at very low noise gains. The part is not generally applicable for unity gain followers or inverters. In general, it should always be used with good low impedance bypass capacitors on the supplies, low impedance feedback values, and minimal capacitive loading. Ground plane construction is recommended, as is a compact layout.

Voltage Noise vs Current Noise

The LT1115's less than 1nV/ $\sqrt{\text{Hz}}$ voltage noise matches that of the LT1028 and is three times better than the lowest voltage noise heretofore available (on the LT1007/1037). A necessary condition for such low voltage noise is operating the input transistors at nearly 1mA of collector currents, because voltage noise is inversely proportional to the square root of the collector current. Current noise, however, is directly proportional to the square root of the collector current. Consequently, the LT1115's current noise is significantly higher than on most monolithic op amps.

APPLICATIONS INFORMATION

Therefore, to realize truly low noise performance it is important to understand the interaction between voltage noise (e_n) , current noise (i_n) and resistor noise (r_n) .

Total Noise vs Source Resistance

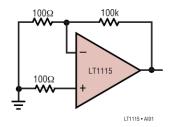
The total input referred noise of an op amp is given by

$$e_t = [e_n^2 + r_n^2 + (i_n R_{eq})^2]^{1/2}$$

where R_{eq} is the total equivalent source resistance at the two inputs

and
$$r_n = \sqrt{4kTR_{eq}} = 0.13\sqrt{R_{eq}}$$
 in nV/\sqrt{Hz} at $25^{\circ}C$

As a numerical example, consider the total noise at 1kHz of the gain of 1000 amplifier shown below.



$$R_{eq} = 100\Omega + 100\Omega || 100k \approx 200\Omega$$

$$r_n = 0.13\sqrt{200} = 1.84 \text{nV}/\sqrt{\text{Hz}}$$

$$e_n = 0.85 \text{nV}/\sqrt{\text{Hz}}$$

$$i_n = 1.0 pA/\sqrt{Hz}$$

$$e_t = [0.85^2 + 1.84^2 + (1.0 \times 2.0)^2]^{1/2} = 2.04 \text{nV}/\sqrt{\text{Hz}}$$

output noise =
$$1000 e_t = 2.04 \mu V / \sqrt{Hz}$$

At very low source resistance ($R_{eq} < 40\Omega$) voltage noise dominates. As R_{eq} is increased resistor noise becomes the largest term—as in the example above—and the LT1115's voltage noise becomes negligible. As R_{eq} is further increased, current noise becomes important. At 1kHz, when R_{eq} is in excess of $20k\Omega$, the current noise component is larger than the resistor noise. The Total Noise vs Matched Source Resistance plot in the Typical Performance Characteristics section, illustrates the above calculations.

The plot also shows that current noise is more dominant at low frequencies, such as 10Hz. This is because resistor noise is flat with frequency, while the 1/f corner of current noise is typically at 250Hz. At 10Hz when $R_{eq} > 1k\Omega$, the current noise term will exceed the resistor noise.

When the source resistance is unmatched, the Total Noise vs Unmatched Source Resistance plot should be consulted. Note that total noise is lower at source resistances below $1k\Omega$ because the resistor noise contribution is less. When $R_S>1k\Omega$ total noise is not improved, however. This is because bias current cancellation is used to reduce input bias current. The cancellation circuitry injects two correlated current noise components into the two inputs. With matched source resistors the injected current noise creates a common-mode voltage noise and gets rejected by the amplifier. With source resistance in one input only, the cancellation noise is added to the amplifier's inherent noise.

In summary, the LT1115 is the optimum amplifier for noise performance—provided that the source resistance is kept low. The following table depicts which op amp manufactured by Linear Technology should be used to minimize noise—as the source resistance is increased beyond the LT1115's level of usefulness.

Best Op Amp for Lowest Total Noise vs Source Resistance

SOURCE RESISTANCE	BEST OP AMP			
(NOTE 1)	AT LOW FREQ (10Hz)	WIDEBAND (1kHz)		
0 to 400Ω	LT1028/1115	LT1028/1115		
400Ω to $4k\Omega$	LT1007/1037	LT1028/1115		
$4k\Omega$ to $40k\Omega$	LT1001*	LT1007/1037		
$40k\Omega$ to $500k\Omega$	LT1012*	LT1001*		
$500 k\Omega$ to $5 M\Omega$	LT1012* or LT1055	LT1012*		
> 5M	LT1055	LT1055		

Note 1: Source resistance is defined as matched or unmatched, e.g., $R_S = 1k\Omega$ means: $1k\Omega$ at each input, or $1k\Omega$ at one input and zero at the other.

TECHNOLOGY TECHNOLOGY

^{*}These op amps are best utilized in applications requiring less bandwidth than audio.

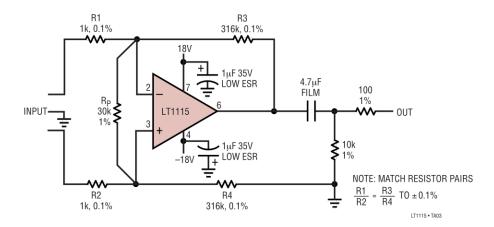
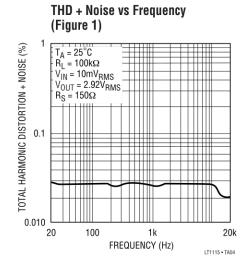


Figure 1. Balanced Transformerless Microphone Preamp





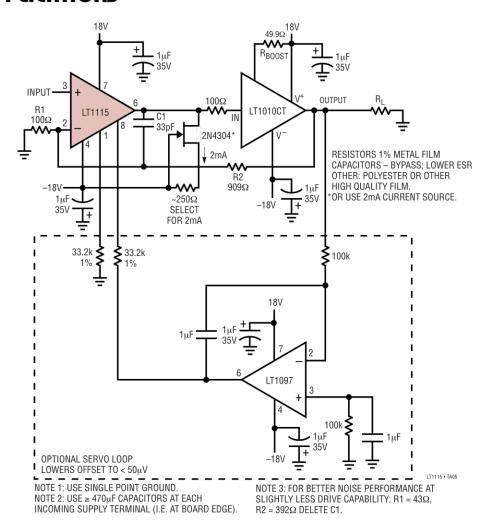
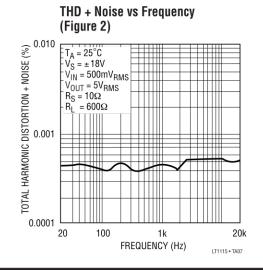


Figure 2. Low Noise DC Accurate x 10 Buffered Line Amplifier



TFAD

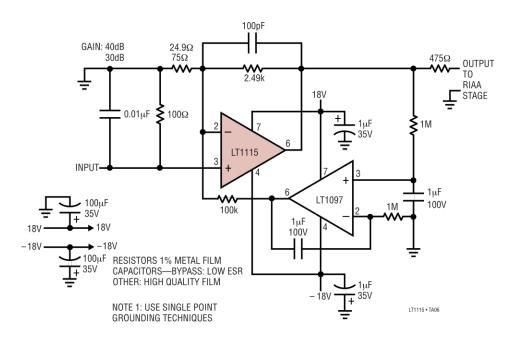
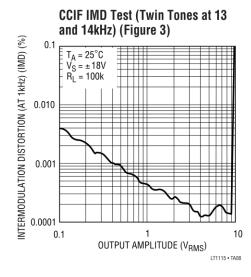
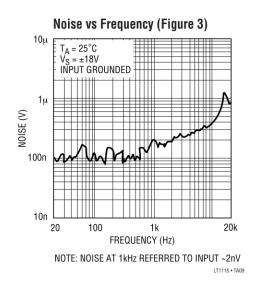


Figure 3. RIAA Moving Coil "Pre-Pre" Amplifier (40/30dB Gain Low Noise Servo'd Amplifier)







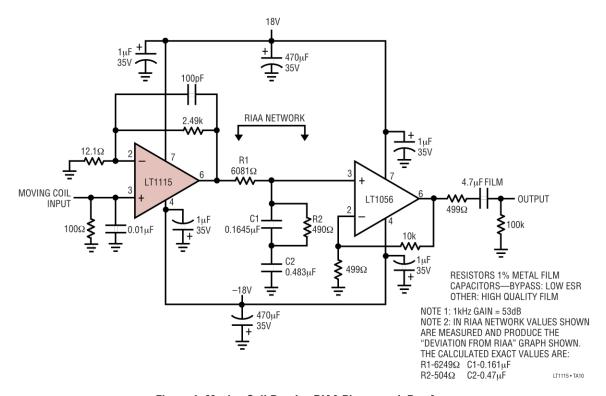
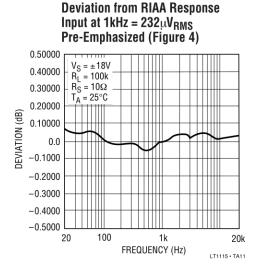
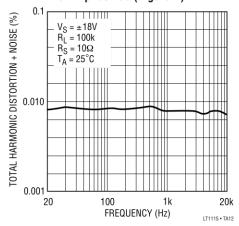


Figure 4. Moving Coil Passive RIAA Phonograph Pre-Amp



THD + Noise vs Frequency Input at 1kHz = 232µV_{RMS} Pre-Emphasized (Figure 4)



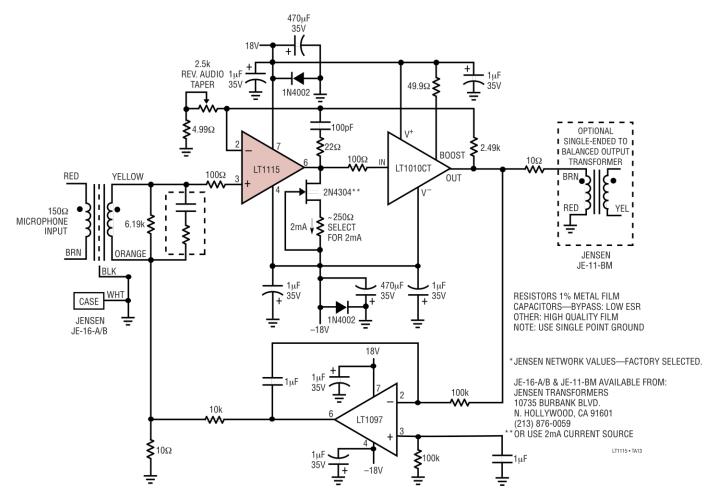
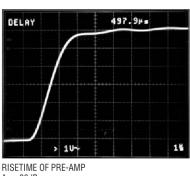


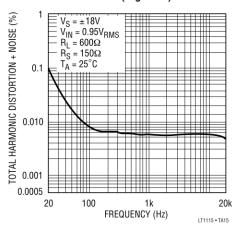
Figure 5. High Performance Transformer Coupled Microphone Pre-Amp

Risetime of High Performance Transformer Coupled Microphone Pre-Amp (Figure 5)

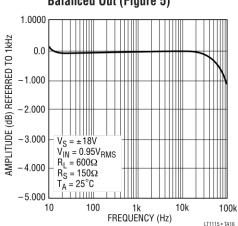


 A_{V} = 20dB $V_{\rm IN}$ = 400mV 2kHz SQUARE WAVE MEASURED AT SINGLE-ENDED OUTPUT BEFORE TRANSFORMER

THD + Noise vs Frequency (Gain = 20dB) Balanced In/ Balanced Out (Figure 5)



Frequency Response (Gain = 20dB) Balanced In/ Balanced Out (Figure 5)





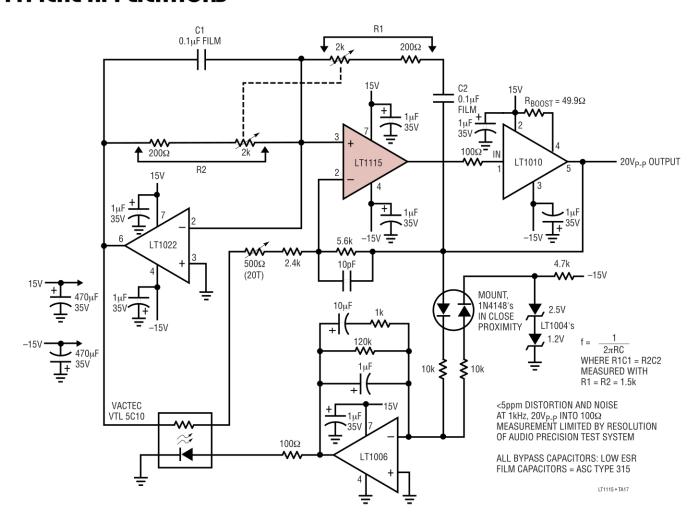
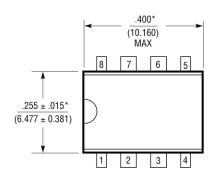


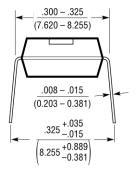
Figure 6. Ultralow THD Oscillator (Sine Wave) (< 5ppm Distortion)

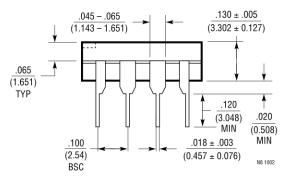
PACKAGE DESCRIPTION

N8 Package 8-Lead PDIP (Narrow .300 Inch)

(Reference LTC DWG # 05-08-1510)







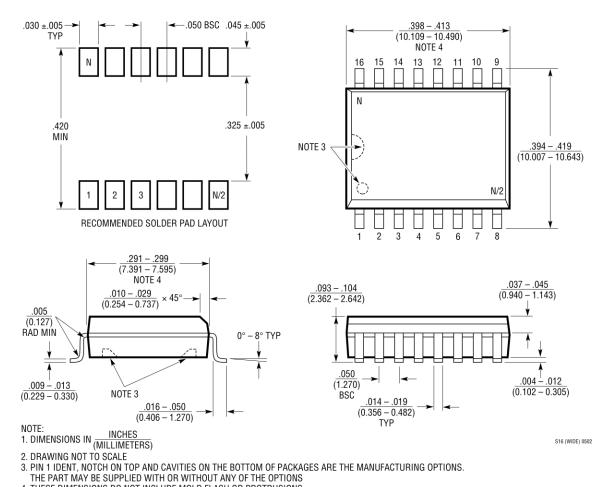
NOTE: 1. DIMENSIONS ARE MILLIMETERS

^{*}THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

PACKAGE DESCRIPTION

SW Package 16-Lead Plastic Small Outline (Wide .300 Inch)

(Reference LTC DWG # 05-08-1620)



- 4. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm)